

FEATURES

- ▶ Wideband frequency range: DC to 30GHz
- ▶ Insertion loss
 - ▶ 0.3dB typical from 0.01GHz to 20GHz
 - ▶ 0.7dB typical from 20GHz to 30GHz
- ▶ Power handling
 - ▶ 37dBm continuous wave typical to 6GHz
 - ▶ >44dBm pulsed typical to 2GHz
- ▶ Flat leakage
 - ▶ 17dBm typical from 0.01GHz to 20GHz
 - ▶ 15dBm typical from 20GHz to 30GHz
- ▶ Recovery time: <10ns
- ▶ Extended operating temperature range: -55°C to +125°C
- ▶ RoHS-compliant, 2mm × 2mm × 0.85mm, 8-lead LFCSP

APPLICATIONS

- ▶ RF transceivers
- ▶ Radar applications
- ▶ Test and measurement

FUNCTIONAL BLOCK DIAGRAM

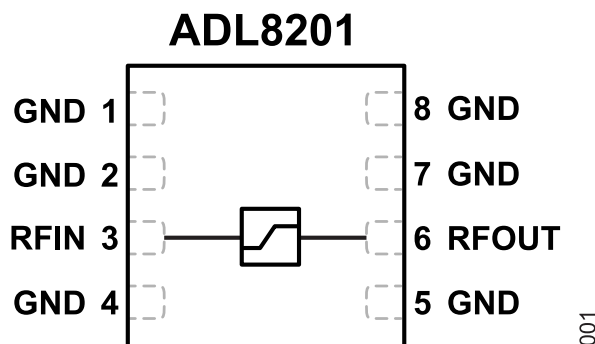


Figure 1. Functional Block Diagram

GENERAL DESCRIPTION

The ADL8201 is a DC to 30GHz, high power, reflective RF limiter ensuring protection of sensitive circuitry.

Typical insertion loss, input return loss (RFIN), and flat leakage are 0.7dB, 18dB, and 15dBm, respectively, from 20GHz to 30GHz. The ADL8201 can withstand 37dBm continuous wave at 6GHz and >44dBm pulsed RF input to 2GHz. The recovery time is less than 10ns. The ADL8201 is internally matched to 50Ω and does not require any external circuitry.

The ADL8201 is fabricated on a gallium arsenide (GaAs) and housed in an RoHS-compliant, 2mm × 2mm × 0.85mm, 8-lead LFCSP. The ADL8201 is specified for operation over an extended temperature range of -55°C to +125°C.

TABLE OF CONTENTS

| | | | |
|---------------------------------------|---|--------------------------------------------------|----|
| Features..... | 1 | Electrostatic Discharge (ESD) Ratings..... | 5 |
| Applications..... | 1 | ESD Caution..... | 5 |
| Functional Block Diagram..... | 1 | Pin Configuration and Function Descriptions..... | 6 |
| General Description..... | 1 | Interface Schematics..... | 6 |
| Specifications..... | 3 | Typical Performance Characteristics..... | 7 |
| 0.01GHz to 20GHz Frequency Range..... | 3 | Theory of Operation..... | 11 |
| 20GHz to 30GHz Frequency Range..... | 3 | Applications Information..... | 12 |
| Power Handling Capabilities..... | 4 | Outline Dimensions..... | 13 |
| Absolute Maximum Ratings..... | 5 | Ordering Guide..... | 13 |

REVISION HISTORY

1/2026—Revision 0: Initial Version

SPECIFICATIONS

0.01GHz TO 20GHz FREQUENCY RANGE

$T_{CASE} = 25^{\circ}\text{C}$ and the device has a 50Ω system, unless otherwise noted.

Table 1. 0.1GHz to 20GHz Frequency Range

| Parameter | Min | Typ | Max | Unit | Test Conditions/Comments |
|-----------------------------------------|------|--------|-----|------------------------|-----------------------------------------------------------------|
| FREQUENCY RANGE (f) | 0.01 | | 20 | GHz | |
| INSERTION LOSS | | 0.3 | | dB | |
| Variation over Temperature | | 0.0036 | | dB/ $^{\circ}\text{C}$ | |
| RETURN LOSS | | | | | |
| RFIN | | 22.5 | | dB | |
| RFOUT | | 22 | | dB | |
| FLAT LEAKAGE | | 17 | | dBm | Input power (P_{IN}) = 30dBm |
| RECOVERY TIME | | <10 | | ns | |
| RF INPUT | | | | | |
| Input Power for 1dB Compression (IP1dB) | | 16 | | dBm | |
| Input Power for 5dB Compression (IP5dB) | | 21 | | dBm | |
| Input Third-Order Intercept (IIP3) | | 38.5 | | dBm | Measurement taken at output power (P_{OUT}) per tone = 0dBm |
| Input Second-Order Intercept (IIP2) | | 81 | | dBm | Measurement taken at P_{OUT} per tone = 0dBm |

20GHz TO 30GHz FREQUENCY RANGE

$T_{CASE} = 25^{\circ}\text{C}$ and the devices is a 50Ω system, unless otherwise noted.

Table 2. 20GHz to 30GHz Frequency Range

| Parameter | Min | Typ | Max | Unit | Test Conditions/Comments |
|----------------------------|-----|------|-----|------------------------|--------------------------------------------------------------------|
| FREQUENCY RANGE | 20 | | 30 | GHz | |
| INSERTION LOSS | | 0.7 | | dB | |
| Variation over Temperature | | 0.01 | | dB/ $^{\circ}\text{C}$ | |
| RETURN LOSS | | | | | |
| RFIN | | 18 | | dB | |
| RFOUT | | 17 | | dB | |
| FLAT LEAKAGE | | 15 | | dBm | $P_{IN} = 30\text{dBm}$ |
| RECOVERY TIME | | <10 | | ns | |
| RF INPUT | | | | | |
| IP1dB | | 15 | | dBm | |
| IP5dB | | 20.5 | | dBm | |
| IIP3 | | 28 | | dBm | Measurement taken at P_{OUT} per tone = 0dBm |
| IIP2 | | 48.5 | | dBm | Measurement taken at P_{OUT} per tone = 0dBm, $f = 24\text{GHz}$ |

SPECIFICATIONS

POWER HANDLING CAPABILITIES

Table 3. Power Survivability vs. Frequency, Pulse Width = 10 μ s, Duty Cycle = 1%, T_{CASE} = 85°C, Single Event (<10sec Operation)

| Frequency | 2GHz | 4GHz | 6GHz |
|-----------------------|--------|---------|-------|
| Power Handling Rating | >44dBm | 43.5dBm | 43dBm |

Table 4. Power Survivability vs. Pulse Width, f = 6GHz, Duty Cycle = 1%, T_{CASE} = 85°C, Single Event (<10sec Operation)

| Pulse Width | 1 μ s | 10 μ s | 100 μ s | 500 μ s |
|-----------------------|-----------|------------|-------------|-------------|
| Power Handling Rating | 44.5dBm | 43dBm | 42dBm | 41dBm |

Table 5. Power Survivability vs. Duty Cycle, f = 6GHz, Pulse Width = 10 μ s, T_{CASE} = 85°C, Single Event (<10sec Operation)

| Duty Cycle | 1% | 10% | 20% | Continuous Wave |
|-----------------------|-------|---------|---------|-----------------|
| Power Handling Rating | 43dBm | 42.5dBm | 41.5dBm | 37dBm |

ABSOLUTE MAXIMUM RATINGS

Table 6. Absolute Maximum Ratings

| Parameter | Rating |
|-----------------|-----------------|
| Temperature | |
| Storage Range | -65°C to +150°C |
| Operating Range | -55°C to +125°C |
| Maximum Channel | 175°C |

Stresses at or above those listed under Absolute Maximum Ratings may cause permanent damage to the product. This is a stress rating only; functional operation of the product at these or any other conditions above those indicated in the operational section of this specification is not implied. Operation beyond the maximum operating conditions for extended periods may affect product reliability.

ELECTROSTATIC DISCHARGE (ESD) RATINGS

The following ESD information is provided for handling of ESD-sensitive devices in an ESD protected area only.

Human body model (HBM) per ANSI/ESDA/JEDEC JS-001.

ESD Ratings for ADL8201

Table 7. ADL8201, 8-Lead LFCSP

| ESD Model | Withstand Threshold (V) | Class |
|-----------|-------------------------|-------|
| HBM | ±1500 | 1C |

ESD CAUTION



ESD (electrostatic discharge) sensitive device. Charged devices and circuit boards can discharge without detection. Although this product features patented or proprietary protection circuitry, damage may occur on devices subjected to high energy ESD. Therefore, proper ESD precautions should be taken to avoid performance degradation or loss of functionality.

PIN CONFIGURATION AND FUNCTION DESCRIPTIONS

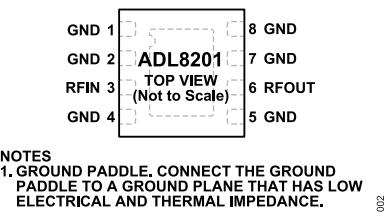


Figure 2. Pin Configuration

Table 8. Pin Function Descriptions

| Pin No. | Mnemonic | Description |
|------------------|---------------|-----------------------------------------------------------------------------------------------------------------------------------------|
| 1, 2, 4, 5, 7, 8 | GND | Ground. Connect the GND pins to a ground plane that has low electrical and thermal impedance. See Figure 3 for the interface schematic. |
| 3 | RFIN | RF Input. RFIN is DC-coupled and matched to 50Ω. See Figure 4 for the interface schematic. |
| 6 | RFOUT | RF Output. RFOUT is DC-coupled and matched to 50Ω. See Figure 4 for the interface schematic. |
| | GROUND PADDLE | Ground Paddle. Connect the ground paddle to a ground plane that has a low electrical and thermal impedance. |

INTERFACE SCHEMATICS



Figure 3. GND Interface Schematic

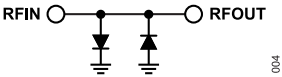


Figure 4. RFIN and RFOUT Interface Schematic

TYPICAL PERFORMANCE CHARACTERISTICS

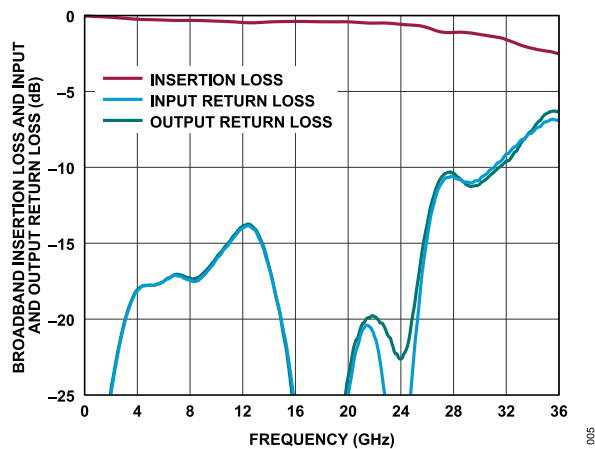


Figure 5. Broadband Insertion Loss and Input and Output Return Loss vs. Frequency

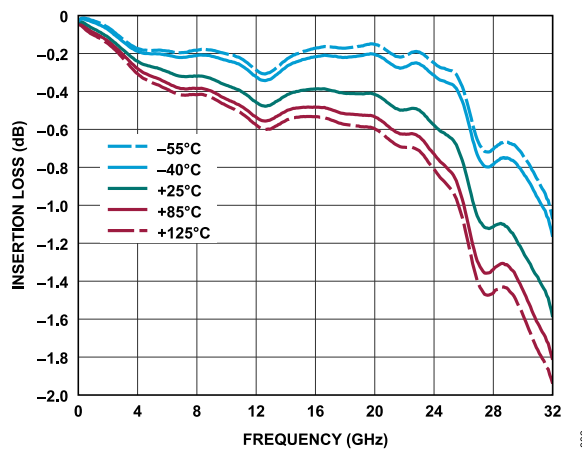


Figure 8. Insertion Loss vs. Frequency for Various Temperatures

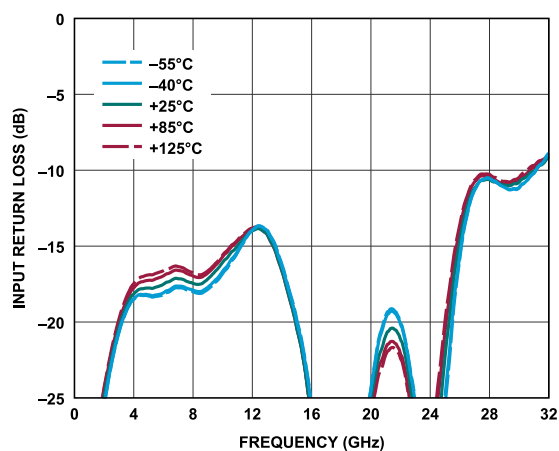


Figure 6. Input Return Loss vs. Frequency for Various Temperatures

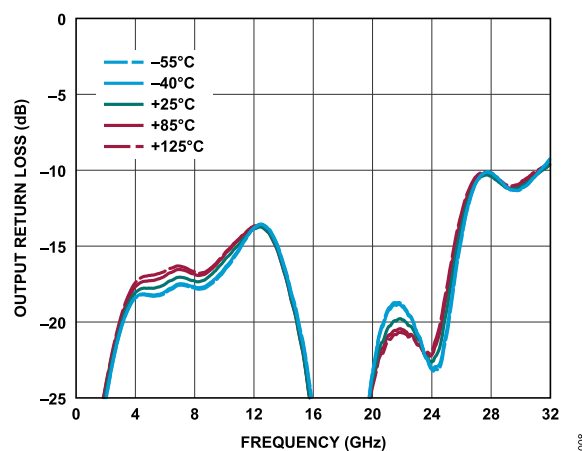


Figure 9. Output Return Loss vs. Frequency for Various Temperatures

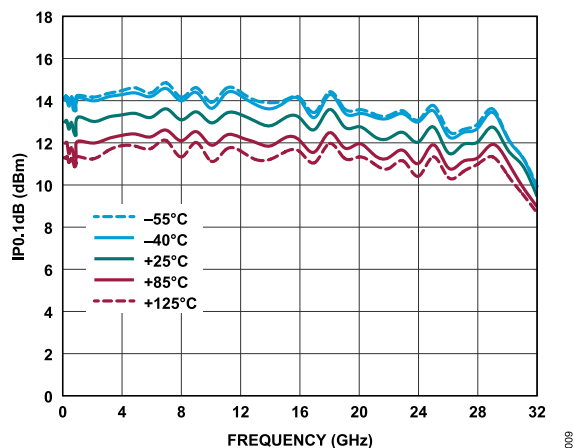


Figure 7. Input Power for 0.1dB Compression ($IP_{0.1dB}$) vs. Frequency for Various Temperatures

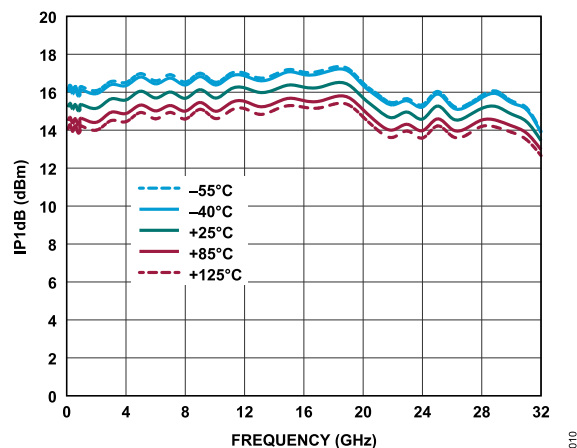


Figure 10. IP_{1dB} vs. Frequency for Various Temperatures

TYPICAL PERFORMANCE CHARACTERISTICS

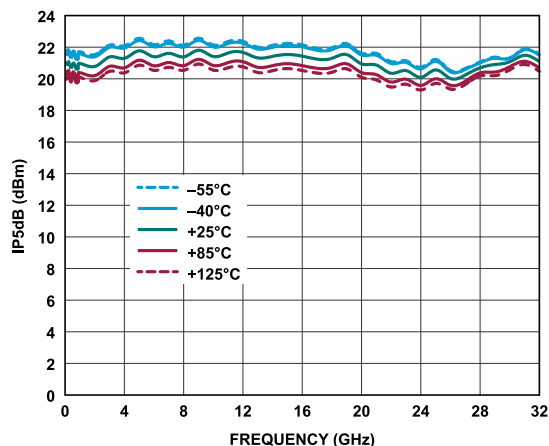


Figure 11. IP5dB vs. Frequency for Various Temperatures

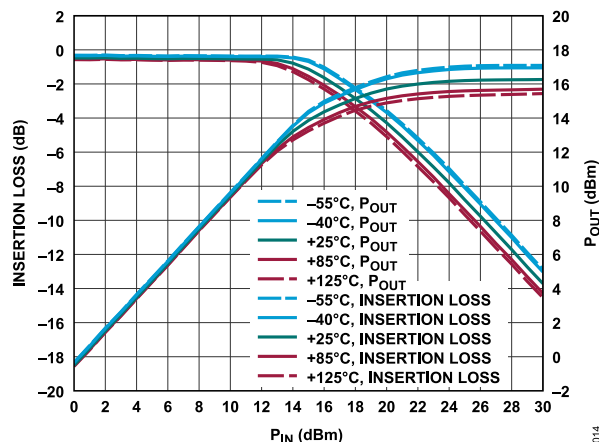


Figure 14. Insertion Loss and P_{OUT} vs. P_{IN} for Various Temperatures, 10GHz

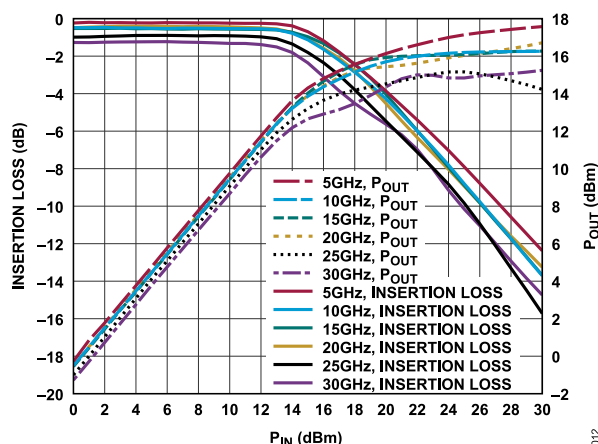


Figure 12. Insertion Loss and P_{OUT} vs. P_{IN} for Various Frequencies

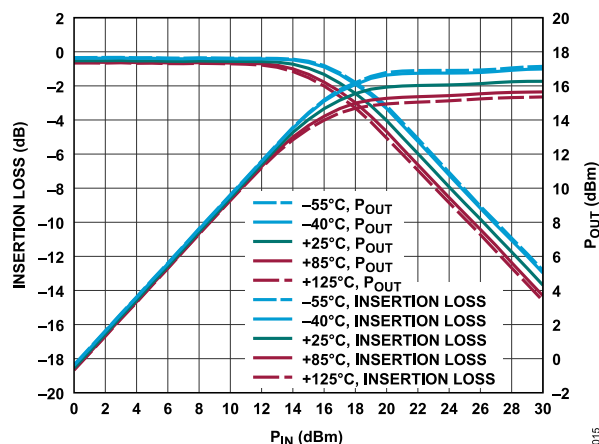


Figure 15. Insertion Loss and P_{OUT} vs. P_{IN} for Various Temperatures, 15GHz

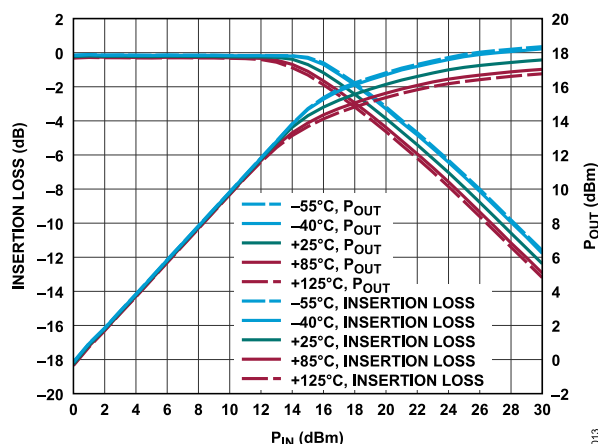


Figure 13. Insertion Loss and P_{OUT} vs. P_{IN} for Various Temperatures, 5GHz

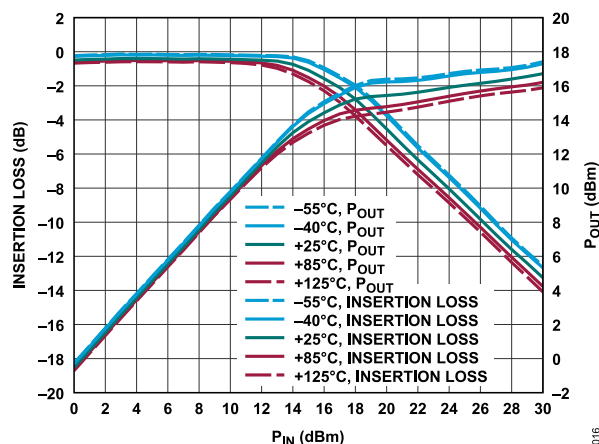


Figure 16. Insertion Loss and P_{OUT} vs. P_{IN} for Various Temperatures, 20GHz

TYPICAL PERFORMANCE CHARACTERISTICS

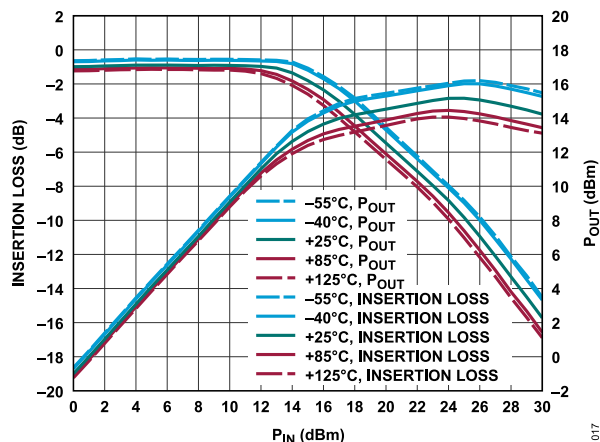


Figure 17. Insertion Loss and P_{OUT} vs. P_{IN} for Various Temperatures, 25GHz

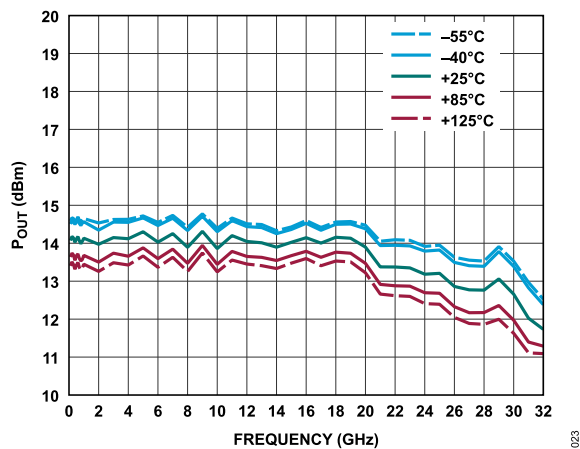


Figure 20. P_{OUT} vs. Frequency for Various Temperatures, 15dBm

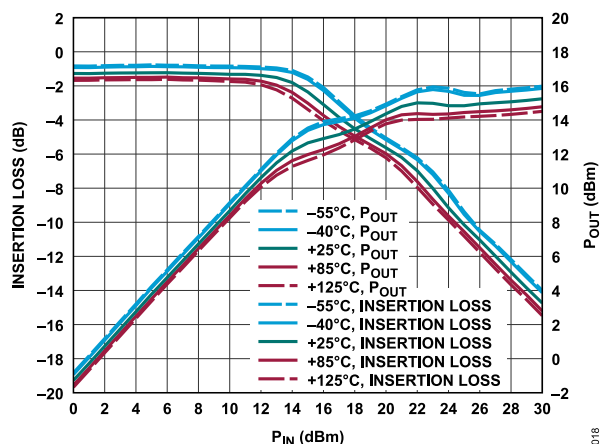


Figure 18. Insertion Loss and P_{OUT} vs. P_{IN} for Various Temperatures, 30GHz

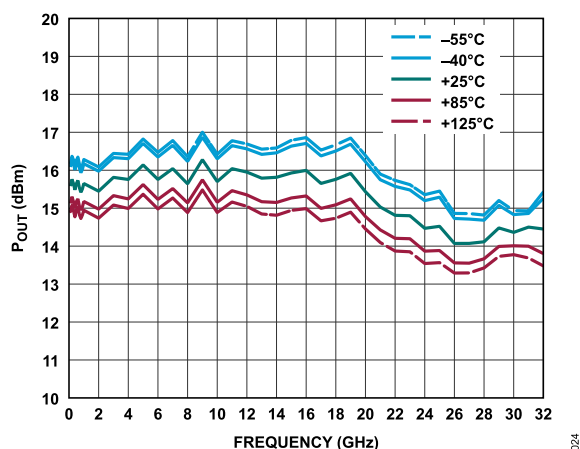


Figure 21. P_{OUT} vs. Frequency for Various Temperatures, 20dBm

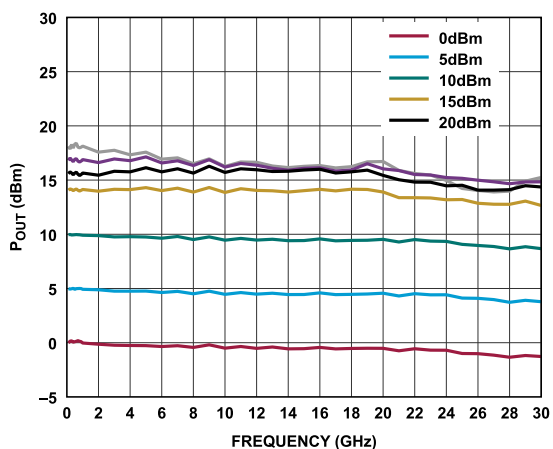


Figure 19. P_{OUT} vs. Frequency for Various P_{IN} Values

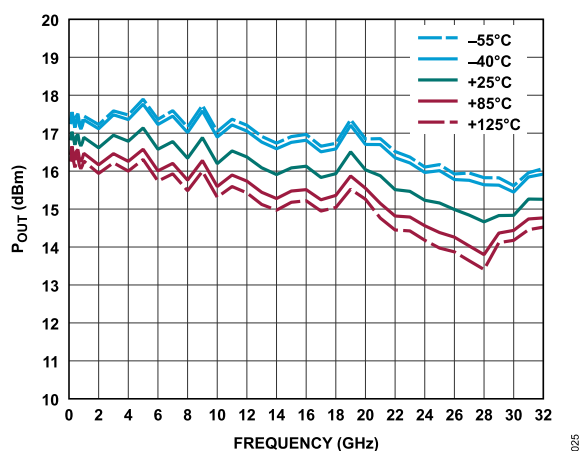


Figure 22. P_{OUT} vs. Frequency for Various Temperatures, 25dBm

TYPICAL PERFORMANCE CHARACTERISTICS

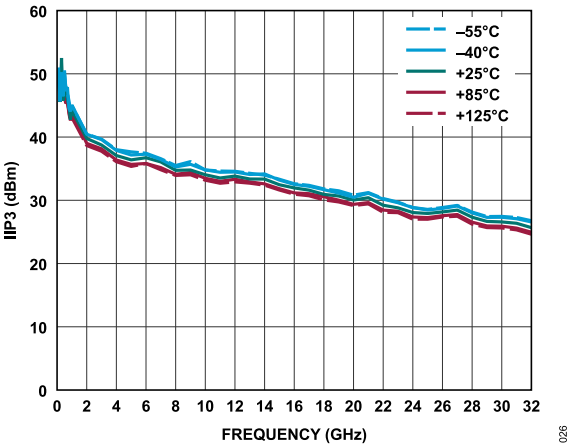


Figure 23. IIP3 vs. Frequency for Various Temperatures

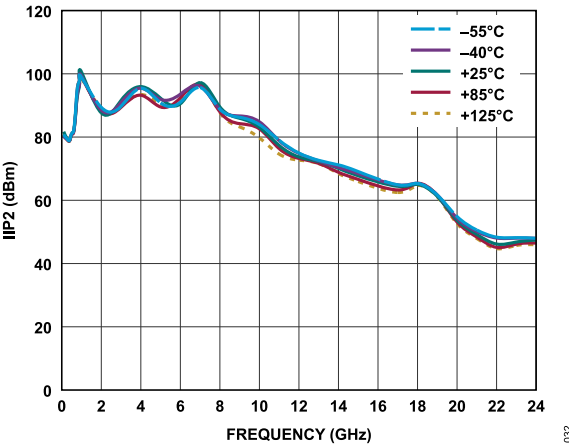


Figure 25. IIP2 vs. Frequency for Various Temperatures

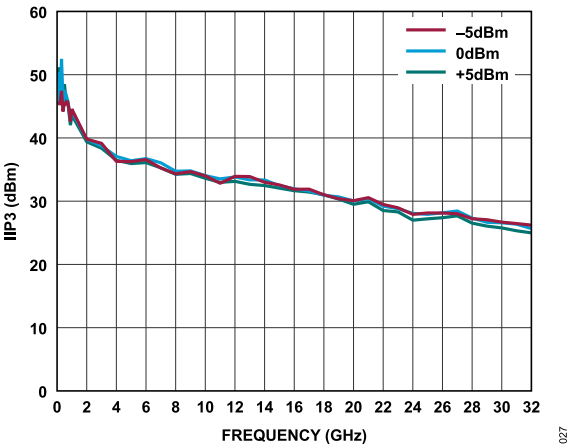


Figure 24. IIP3 vs. Frequency for Various P_{1M} Values per Tone

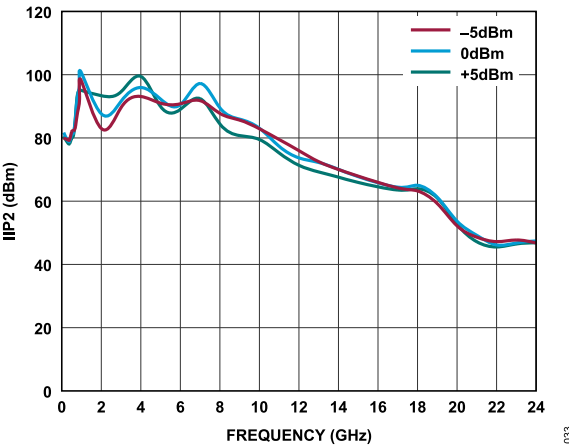


Figure 26. IIP2 vs. Frequency for Various P_{1M} Values per Tone

THEORY OF OPERATION

The ADL8201 is a reflective RF limiter. [Figure 27](#) shows the simplified architecture of the ADL8201.

The ADL8201 has DC-coupled, single-ended input and output ports with impedance that is nominally equal to 50Ω up to 30GHz. No external matching components are required.

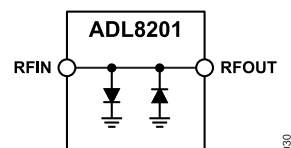


Figure 27. Simplified Architecture

APPLICATIONS INFORMATION

The basic connections for operating the ADL8201 over the specified frequency range are shown in [Figure 28](#). No external biasing circuitry is required. [Figure 28](#) represents the configuration used to characterize and qualify the ADL8201.

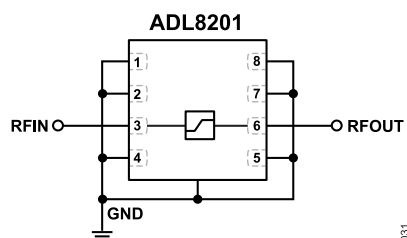


Figure 28. Typical Application Circuit

OUTLINE DIMENSIONS

| Package Drawing Option | Package Type | Package Description |
|-------------------------|--------------|--------------------------------------|
| CP-8-30 | LFCSP | 8-Lead Lead Frame Chip Scale Package |

For the latest package outline information and land patterns (footprints), go to [Package Index](#).

ORDERING GUIDE

| Model ^{1, 2} | Temperature Range | Package Description | Packing Quantity | Package Option |
|-----------------------|-------------------|----------------------------------|------------------|----------------|
| ADL8201ACPZN | -55°C to +125°C | 8-Lead LFCSP, 2mm × 2mm × 0.85mm | Tape, 1 | CP-8-30 |
| ADL8201ACPZN-R7 | -55°C to +125°C | 8-Lead LFCSP, 2mm × 2mm × 0.85mm | Reel, 3000 | CP-8-30 |

¹ Z = RoHS Compliant Part.

² The lead finish of the ADL8201ACPZN and ADL8201ACPZN-R7 is nickel palladium gold.

Legal Terms and Conditions

Information furnished by Analog Devices is believed to be accurate and reliable "as is". However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners. All Analog Devices products contained herein are subject to release and availability.